

Study on the Effect of Bi₂O₃ Additive on the Microstructure, Structural and Magnetic Properties of Ni_{0.35}Cu_{0.15}Zn_{0.5} Ferrite Sintered at 1100°C

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Abstract

The effect of variation of addition of Bi₂O₃ (0 wt.%, 1 wt.%, 2 wt.% and 3 wt.%) on the microstructure, structural and magnetic properties of Ni_{0.35}Cu_{0.15}Zn_{0.50}Fe₂O₄ has been reported. The Scanning Electron Micrograph (SEM) of the samples reveals that the grain size increases with increasing additive up to 2 wt.% addition. Above 2 wt.% addition, no significant change in grain size is evident. The X-Ray Diffraction (XRD) pattern confirms the crystallization of the samples in single-phase cubic spinel structure. The lattice constant of Ni_{0.35}Cu_{0.15}Zn_{0.50}Fe₂O₄ increases gradually with increasing Bi₂O₃ content up to 2 wt.% addition. A further addition shows decrease in lattice constant. Again, the addition of Bi₂O₃ produced a thick liquid phase layer at the grain boundaries and retarded mass transfer during sintering. Thus the X-ray diffraction peaks exhibited reduced intensity. Bi₂O₃ promoted grain growth via liquid phase sintering, and the addition of the optimum content could enhance the density of the sample and reduces its porosity. The Energy Dispersive X-ray Spectroscopy (EDS) analysis ensures proper doping profile of the prepared specimens. The Curie temperature has been investigated from temperature dependent permeability analysis. Undoped Ni_{0.35}Cu_{0.15}Zn_{0.50}Fe₂O₄ shows Curie temperature of 239°C and increases with increase in doping percent of Bi₂O₃. 3 wt.% doping shows Curie temperature of 245°C.

Keywords: XRD, SEM, EDS, Spinel Structure, Porosity, Curie Temperature (T_c), Permeability.

1. Introduction

Study of the polycrystalline spinel ferrite has great importance because of its extensive application in many electronic devices. Due to their amazing magnetic and electric properties, spinel ferrites have become a subject of both theoretical and experimental investigation for application purposes [1–5]. They are preferred because of their high permeability and saturation magnetization in the radio-frequency (RF) region, high electrical resistivity, mechanical hardness and chemical stability. Ferrites are also useful to prevent and eliminate RF interference to audio systems.

Miniaturized components are highly in demand, such as, portable computer (PC), liquid crystal display (LCD), plasma display panel (PDP) and personal digital assistant (PDA) etc. The circuits of these equipments have to consider miniature dc–dc converters, inductors for filters and signal amplifying power inductors. Therefore, it is necessary to realize the miniaturization of electromagnetic components. At present, MnZn ferrites have been widely used in the mini dc–dc converters and inductors [6]. However, NiCuZn ferrites can offer better miniaturization prospects, since they have high electrical resistivity and can miniaturize magnetic components without a bobbin [7–10].

Because of the AB₂O₄ crystal structure of Ni-Cu-Zn ferrite, they show various magnetic properties depending on chemical composition and cation distribution in tetrahedral

A and octahedral B sites [11]. Several researchers have prepared Ni-Cu-Zn ferrite [12–16]. Zn²⁺ is used to improve electromagnetic properties as well as densification in the ferrite. It is substituted in spinel ferrite to improve magnetization [17]. It also lowers magnetostriction and anisotropy in ferrites [18]. Goev et al. [19] stated that initial permeability increased and hysteresis loss decreased with increasing Zn concentration in Ni_{0.85-y}Cu_{0.15}Zn_yFe₂O₄ ferrite. Cu is conventionally used to improve densification as well as electromagnetic properties [20].

Besides, the chemical composition [21], sintering process [21–25], the additive are also important here, since it influences the microstructure and magnetic properties of NiCuZn ferrites. Recently, additives with a low melting point, such as PbO [22, 23], V₂O₅ [24–28], B₂O₃ [29] and Bi₂O₃ [30–39], have been reported to obtain NiZn ferrites of high performance.

Here in the present research work, we have investigated the effect of Bi₂O₃ additive on microstructure, crystal structure, densification and magnetic properties of Ni_{0.35}Cu_{0.15}Zn_{0.5} ferrite sintered at 1100°C.

2. Experimental Detail

The Ni_{0.35}Cu_{0.15}Zn_{0.50}Fe₂O₄+ x% wt. of Bi₂O₃ (where x= 0, 1, 2 and 3) samples were synthesized using the standard solid-state reaction technique. Powders of NiO(99.99%), CuO(99.99%), ZnO(99.99%), Fe₂O₃(99.99%) and Bi₂O₃(99.99%) are available at Atomic Energy Centre, Dhaka, which are collected from E. Mark of Germany were

used as raw materials. Stoichiometric amounts of required powders were mixed by hand milling and ball milling.

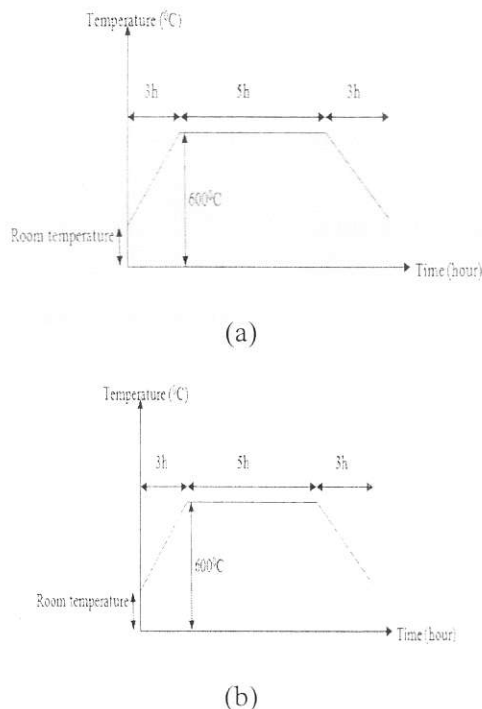


Fig. 1: Time vs. temperature profile for (a) pre-sintering and (b) sintering.

The mixed and dried powder was pressed into disc shape. The disc shaped sample was pre-sintered using NABERTHERM ($300^{\circ}\text{C} - 3000^{\circ}\text{C}$) furnace with temperature profile as shown in fig. 1(a). The pre-sintered sample is then powdered and reshaped into desired shape and then sintering is performed with temperature profile as shown in fig. 1(b). The samples were polished and then thermal etching was performed. The morphological properties and EDS were studied by Scanning Electron Microscope named "FEI Quanta Inspect", Model is S-50.

To study the crystalline phases of the prepared samples, X-ray diffraction (XRD) pattern has been recorded at room temperature with CuK_{α} radiation of wavelength $\lambda = 1.54178 \text{ \AA}$ with primary beam power of 40 kV and 30 mA using a Philips PW3040 X'Pert PRO X-ray diffractometer. Resolution of the scan was set to 0.01° with a sampling pitch of 0.02° and time for each step data collection was 1.0 sec. A 2θ scan was taken from 10° to 90° to get possible fundamental peaks where Ni filter was used to reduce CuK_{β} radiation. All the data of the samples were analyzed using computer software "X'PERT HIGHSCORE".

The temperature-dependent initial permeability was measured using WAYNE KERR INDUCTANCE ANALYZER 3255B, a small oven and a thermocouple based thermometer at a constant frequency (100 kHz). We used AC signal of 100 mV of a sinusoidal wave. The Curie temperature (T_c) of the

samples was determined from the temperature-dependent initial permeability as a function of temperature measurements. Generally a heating of $\approx 2^{\circ}\text{C} / \text{min}$ was used. Near the Curie temperature heating rate was less than $1^{\circ}\text{C} / \text{min}$.

3. Result and Discussion

XRD-Pattern

Eight fundamental reflections from the planes of (111), (220), (311), (222), (400), (422), (511) and (440) are evident from the fig. 2 which strongly determines the cubic spinel structure [40]. These peaks correspond to spinel phases. Thus the analysis of XRD patterns indicated that the studied $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x\text{Bi}_2\text{O}_3$ ferrite samples with $x = 0, 1, 2$ and 3 wt. % has single-phase cubic spinel structures with no presence of undesired phases.

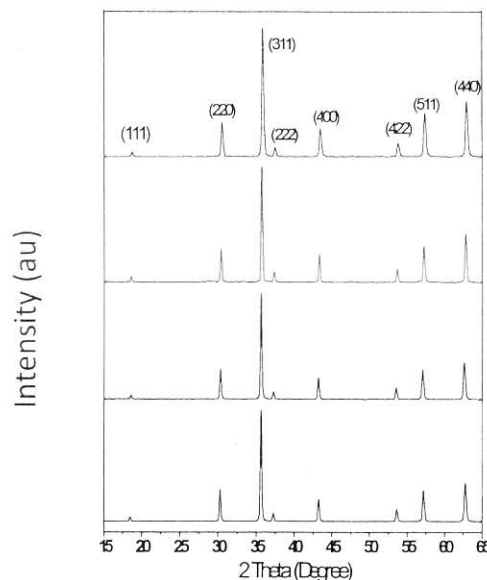


Fig. 2: Comparison of XRD patterns of $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x\text{Bi}_2\text{O}_3$ ferrite samples with $x = 0, 1, 2$ and 3 wt. % respectively.

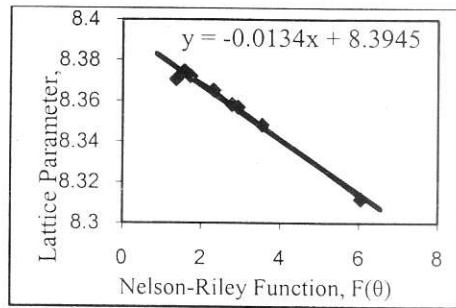
With increasing wt.% of Bi_2O_3 the intensity becomes gradually weaker. It could be interpreted that, the excessive content of Bi_2O_3 produces a thick liquid-phase and retards the grain growth, resulting in a decrease in intensity of the diffraction peaks [41].

Lattice Parameters

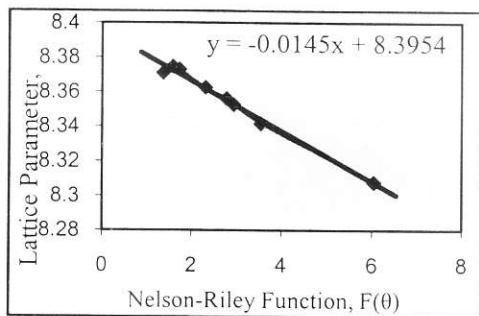
The values of the lattice parameter obtained from each plane are plotted against Nelson-Riley function [42] $F(\theta) = \frac{1}{2}[\cos^2\theta/\sin\theta + \cos^2\theta/\theta]$, where θ is the Bragg's angle. The values of lattice parameters were then estimated from the extrapolation of these lines to $F(\theta) = 0$ or, $\theta = 90^{\circ}$.

Extrapolation provides lattice parameters 8.3945 \AA , 8.3954 \AA , 8.3968 \AA and 8.3895 \AA respectively for 0 wt. %, 1 wt. %, 2 wt. % and 3 wt. % addition of Bi_2O_3 with $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4$. Thus the lattice parameter increases

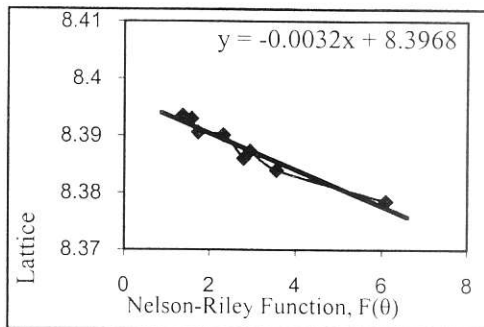
with increase of Bi₂O₃ content within Ni_{0.35}Cu_{0.15}Zn_{0.50}Fe₃O₄ up to 2 wt. %. This is very much expected since the ionic radius of Bi (1.17 Å) is higher than ionic radius of Ni (0.83 Å), Cu (0.87 Å) and Zn (0.88 Å) [43]. Thus addition Bi₂O₃ increases the lattice parameter.



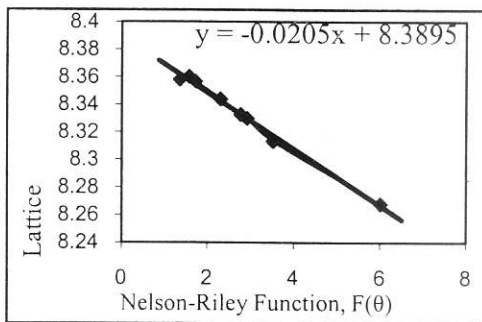
(a)



(b)



(c)



(d)

Fig. 3: Lattice parameter, a Vs. Nelson-Riley function plot of Ni_{0.35}Cu_{0.15}Zn_{0.50}Fe₃O₄+x Bi₂O₃ sample with, (a) x = 0 wt. %, (b) x = 1 wt. %, (c) x = 2 wt. % and (d) x = 3 wt. %.

In case of 3 wt. % addition of Bi₂O₃ with Ni_{0.35}Cu_{0.15}Zn_{0.50}Fe₃O₄ different situation arises. Here, the value of lattice parameter falls. In fact, Bi₂O₃ provide sintering aid. Ni-Cu-Zn ferrite with a only 0.8 wt. % addition of Bi₂O₃ shows a reduction in sintering temperature up to 150⁰C [44]. When 3 wt. % of Bi₂O₃ is added then reduction in sintering is very high. Thus at sintering temperature of 1100⁰C may be over sintering takes place and thus lattice parameter decreases.

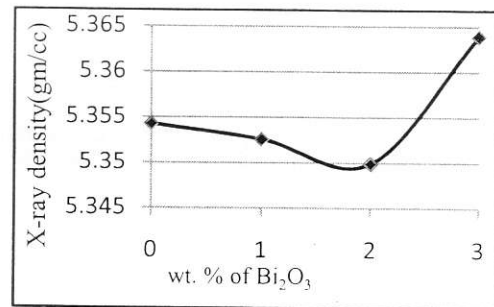
Density and Porosity

The x-ray density also called theoretical density is determined using,

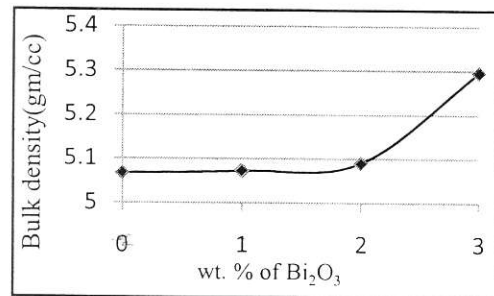
$$\rho_x = \frac{ZM}{Na^3} \dots \dots \dots (1)$$

where, N is Avogadro's number (6.023x10²³ mol⁻¹), M is the molecular weight and Z is the number of atoms per unit cell, which is 8 for the spinel cubic structure.

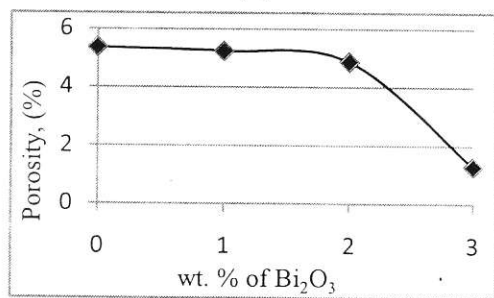
Bulk density is calculated as the ratio of mass to weight. Calculated bulk density then plotted against wt.% addition of Bi₂O₃ in Fig. 4(b).



(a)



(b)



(c)

Fig. 4: Variation of (a) theoretical density, (b) bulk density and (c) porosity for different (0, 1, 2 and 3) wt. % addition of Bi₂O₃ with Ni_{0.35}Cu_{0.15}Zn_{0.50}Fe₃O₄.

The addition of Bi_2O_3 additive enhances the mass transfer and sintering via liquid phase to get higher density at the same temperature. Because the Bi_2O_3 additive remains liquid when the temperature is over 820°C , it forms low melting eutectics. This phenomenon agrees with the results of XRD measurement. The improvement in density of Bi-doped samples could be attributed to the following reasons: (1) the main reason is the improvement in the rate of grain growth due to the formation of liquid phase and (2) the secondary reason is the higher density of Bi_2O_3 (8.9 g cm^{-3}) in comparison with $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4$ ferrite density. Wang et al have proved that the formation of the Pb_2O_3 liquid phase could be attributed to the densification of NiZn ferrite at a lower temperature through particle rearrangement, solution-precipitation and solid skeleton process. For the similar reasons porosity on the other hand gradually decreases with increase in wt. % doping of Bi_2O_3 .

Porosity P is determined using,

$$P = \left(1 - \frac{\rho_B}{\rho_X}\right) \times 100\% \dots \dots (2)$$

where, ρ_B is the bulk density measured by usual mass volume ratio and ρ_X is the theoretical density or X-ray density.

SEM Micrograph Analysis

The microstructures of $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x \text{ Bi}_2\text{O}_3$ ($x = 0, 1, 2$ and 3) sintered at 1100°C has been represented in Fig. 5. Figure shows the variation of grain size with doping percentage. For pure $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4$ the grain size is relatively small as shown in Fig. 5(a). Fig. 5(b) and Fig. 5(c) shows gradual increase in grain size that corresponds to 1wt. % and 2 wt. % addition of Bi_2O_3 . In case of 3 wt. % addition of Bi_2O_3 no significant change in grain size occurs which is evident in Fig. 5(d). This is may be due the presence of excessive amount of Bi_2O_3 , of which melting point is only 820°C whereas sintering temperature is 1100°C . Thus this excessive amount of Bi_2O_3 at such high sintering temperature creates a liquid environment which prevents further increase in grain size.

Again for the samples with small grains, pores are found usually at the grain boundary. For the samples with large grains, the majority of the pores are trapped inside the grains at large distance from the grain boundary, which affects the value of permeability, density dielectric constant and resistivity.

This study postulates different mechanisms pertaining to the grain growth in the case of NiCuZn ferrites which depends on the amount of liquid phase present in the system [31-33, 45].

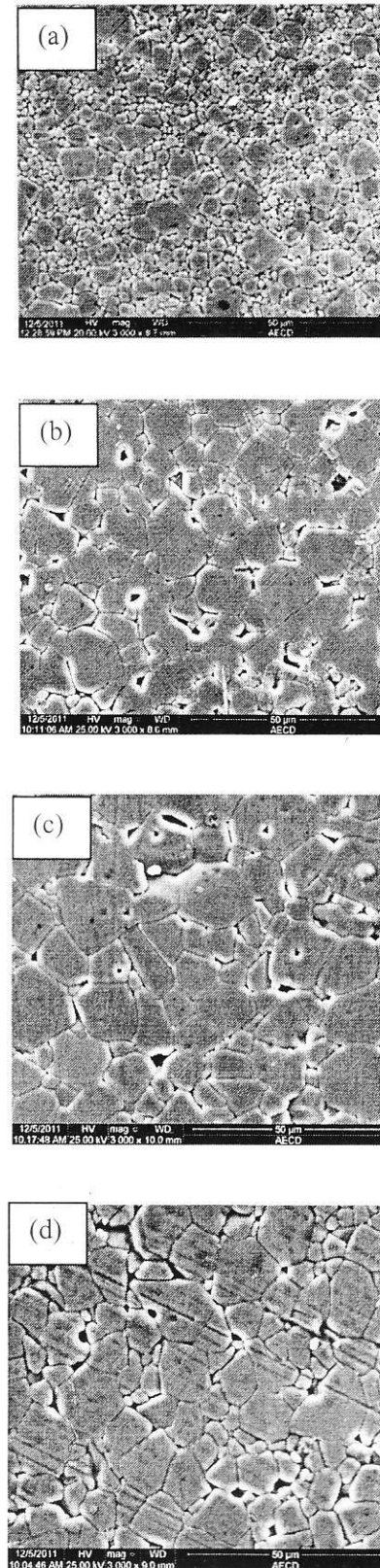


Fig. 5: SEM micrograph of $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x \text{ wt. } \% \text{ Bi}_2\text{O}_3$ sintered at 1100°C , where, (a) $x = 0$, (b) $x = 1$, (c) $x = 2$ and (d) $x = 3$.

EDX Analysis

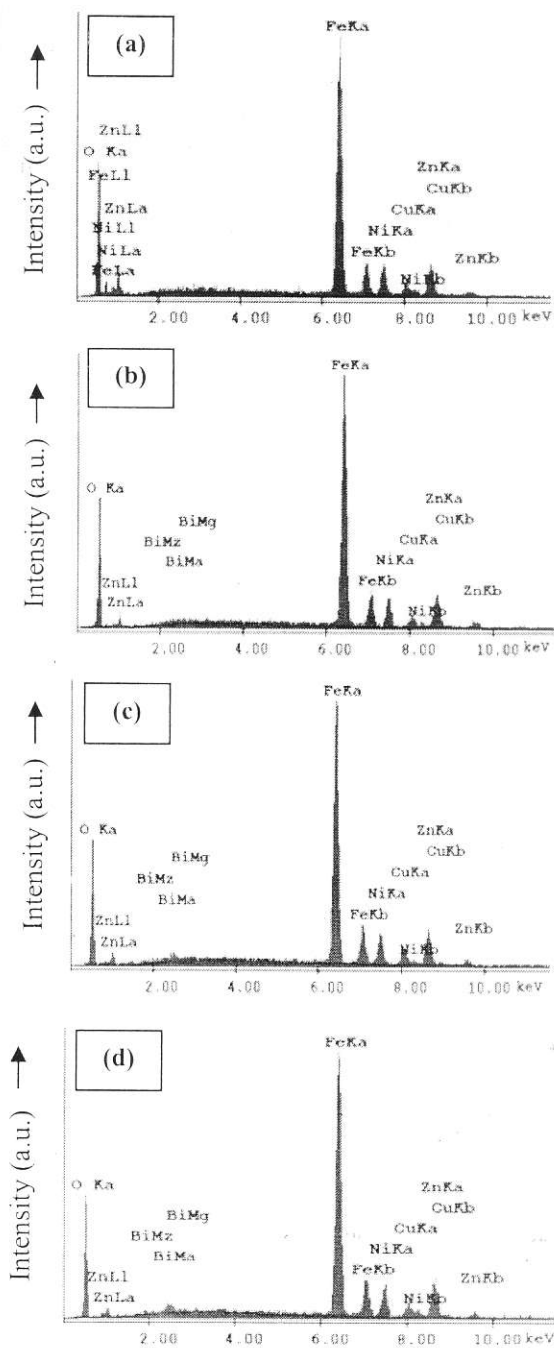
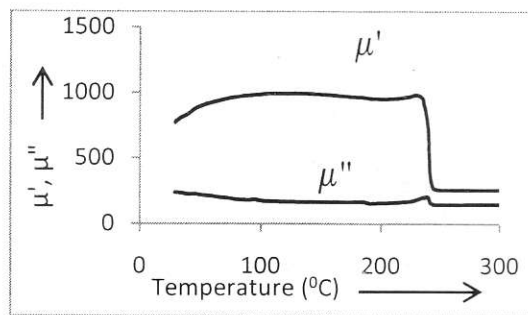
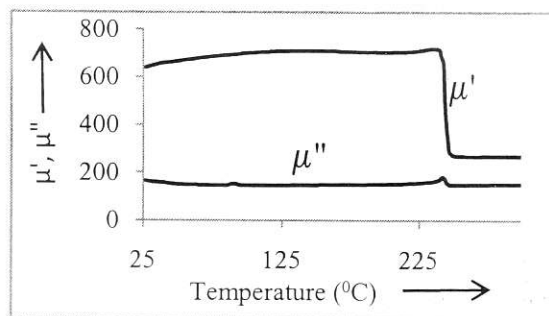


Fig. 6: EDX analysis of $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x$ wt. % Bi_2O_3 sintered at 1100°C , where, (a) $x = 0$, (b) $x = 1$, (c) $x = 2$ and (d) $x = 3$.

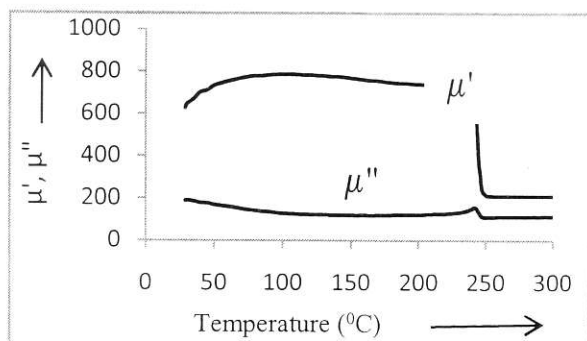
The EDX analysis images are represented in Fig. 6. Fig. 6(a) shows no presence of Bi content which ensures 0 wt. % addition of Bi_2O_3 in this sample as expected. The image provided by SEM does not include any scaling in vertical axis but provide quantified data. The quantified data for Bi content provided by SEM are represented in table 1.



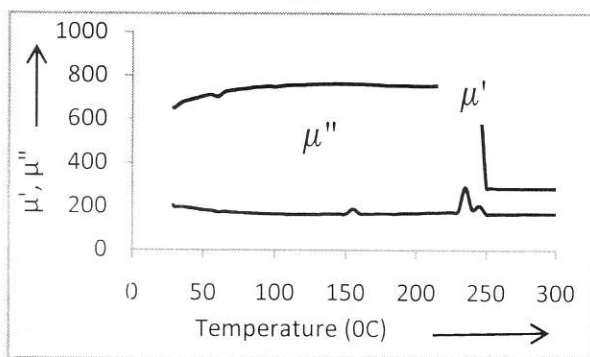
(a)



(b)



(c)



(d)

Fig. 7: Temperature dependence of permeability for $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x$ wt. % Bi_2O_3 sintered at 1100°C , where, (a) $x = 0$, (b) $x = 1$, (c) $x = 2$ and (d) $x = 3$.

Table 1: Wt. % and atomic % presence of Bi content in $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x \text{Bi}_2\text{O}_3$ for $x=0, 1, 2$ and 3 wt. %.

Wt. % of Bi_2O_3 , (x) in $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x \text{Bi}_2\text{O}_3$	Wt. % of Bi	Atomic % of Bi
0	0	0
1	0.63	0.16
2	0.81	0.20
3	1.11	0.28

The table ensures the proper doping of the sample with Bi_2O_3 .

Temperature Dependent Permeability

The variation of real and imaginary permeability with variation of temperature are depicted in Fig. 7. The figure reveals that, highest permeability is found with pure $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4$. For each % of doping, frequency dependent real permeability up to Curie temperatures are nearly same and are less than 0 % doping.

Curie Temperature

From curves of temperature dependent permeability (Fig. 7) Curie temperatures are determined. Determined Curie temperatures are given in Table 2.

Table 2: Curie temperatures for $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x$ wt. % of Bi_2O_3 ($x=0, 1, 2$ and 3) sintered at 1100°C .

Wt. % of Bi_2O_3 , (x) in $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4 + x \text{Bi}_2\text{O}_3$	Determined Curie Temperature, T_c ($^\circ\text{C}$)
0	239
1	243
2	243
3	245

The table clearly shows that, with increase in doping % of Bi_2O_3 the Curie temperature of the samples are increases.

4. Conclusions

In investigating the grain growth, densification and magnetic properties of $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}$ ferrites doped with different contents of Bi_2O_3 shows that, addition of Bi_2O_3 additive, to $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}\text{Fe}_3\text{O}_4$, due to its liquid phase sintering, enhances the diffraction intensity while excessive (>1 wt.%) content of Bi_2O_3 produces a thick liquid phase layer at the grain boundaries and retards mass transfer during sintering. Thus the X-ray diffraction peaks exhibit reduced intensity. Addition of Bi_2O_3 does not introduce any phase mismatching within the crystal structure. Bi_2O_3 promotes grain growth via liquid phase sintering and

addition of Bi_2O_3 enhances density and reduces porosity. Microstructure study reveals that the grain size increases with increasing Bi_2O_3 up to 2 wt.% addition. A further addition does not show any significant increase in grain size. Again in case of small sized grain, the pores are relatively high and are distributed at the boundary of the grain. On the other hand, number of pores gradually decreases with increasing grain size and are distributed mostly within the grain. EDX analysis clearly ensures proper doping of the dopant. Temperature dependent permeability curves shows that, below Curie temperature, undoped $\text{Ni}_{0.35}\text{Cu}_{0.15}\text{Zn}_{0.50}$ ferrite shows relatively higher permeability than doped one. But with increasing doping percent of Bi_2O_3 , Curie temperature gradually increases.

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